

Analysis of barrier inhomogeneities of P-type Al/4H-SiC Schottky barrier diodes

Ziko, Mehadi Hasan; Koel, Ants; Rang, Toomas; Toompuu, Jana Silicon Carbide and Related Materials 2019 : Selected peer-reviewed papers from International Conference on Silicon Carbide and Related Materials 2019 (ICSCRM 2019), September 29 - October 4, 2019, Kyoto, Japan Materials science forum 2020 / p. 960-972 <https://doi.org/10.4028/www.scientific.net/MSF.1004.960>
[Conference proceedings at Scopus](#) [Article at Scopus](#)

Effects of the inclusion of armchair graphene nanoribbons on the electrical conduction properties of NN-heterojunction 4H-6H/SiC diodes

Rashid, Muhammad Haroon; Koel, Ants; Rang, Toomas Advanced Materials and Processing Technologies : 2nd International Conference on Sensors, Materials and Manufacturing (ICSMM 2018, November 19-21, 2018, Taiwan); International Conference on Materials Sciences and Nanomaterials (ICMSN 2018, July 11-13, 2018, United Kingdom) and the 2nd International Conference on Materials and Intelligent Manufacturing (ICMIM 2018, August 24-26, 2018, Japan) 2019 / p. 29-35 : ill <https://doi.org/10.4028/www.scientific.net/MSF.962.29> [Conference proceeding at Scopus](#) [Article at Scopus](#)

Modeling and simulations of 4H-SiC/6H-SiC/4H-SiC single quantum-well light emitting diode using diffusion bonding technique

Rashid, Muhammad Haroon; Koel, Ants; Rang, Toomas Micromachines 2021 / art. 1499 <https://doi.org/10.3390/mi12121499> [Journal metrics at Scopus](#) [Article at Scopus](#) [Journal metrics at WOS](#) [Article at WOS](#)

Nano- and Micro-Scale simulations of Ge/3C-SiC and Ge/4H-SiC NN-heterojunction diodes

Rashid, Muhammad Haroon; Koel, Ants; Rang, Toomas Silicon Carbide and Related Materials 2019 : 18th International Conference on Silicon Carbide and Related Materials 2019 (ICSCRM 2019), Kyoto, Japan, September 29 - October 4, 2019 Materials science forum 2020 / p. 490-496 <https://doi.org/10.4028/www.scientific.net/MSF.1004.490> [Conference proceedings at Scopus](#) [Article at Scopus](#)

Nano and micro-scale simulations of Si/4H-SiC and Si/3C-SiC NN-heterojunction diodes

Rashid, Muhammad Haroon; Koel, Ants; Rang, Toomas Silicon Carbide and Related Materials 2018 : 12th European Conference on Silicon Carbide and Related Materials (ECSCRM 2018) : Selected, peer reviewed papers from the European Conference on Silicon Carbide and Related Materials (ECSCRM 2018), September 2-6, 2018, Birmingham, UK 2019 / p. 357-361 <https://doi.org/10.4028/www.scientific.net/MSF.963.357> [Conference proceeding at Scopus](#) [Article at Scopus](#)

Nanoscale and microscale simulations of N-N junction heterostructures of 3C-4H silicon carbide

Rashid, Muhammad Haroon; Koel, Ants; Rang, Toomas; Gähwiler, Reto; Grosberg, Martin; Jõemaa, Rauno Materials and contact characterisation VIII 2017 / p. 235-248 : ill <https://doi.org/10.2495/MC170241> [Conference proceedings at Scopus](#) [Article at Scopus](#)

Simulations of benzene and hydrogen-sulfide gas detector based on single-walled carbon nanotube over intrinsic 4H-SiC substrate

Rashid, Muhammad Haroon; Koel, Ants; Rang, Toomas; Ziko, Mehadi Hasan Micromachines 2020 / art. 453, 13 p. : ill <https://doi.org/10.3390/mi11050453> [Journal metrics at Scopus](#) [Article at Scopus](#) [Journal metrics at WOS](#) [Article at WOS](#)

Simulations of heterostructures based on 3C-4H and 6H-4H silicon carbide polytypes

Rashid, Muhammad Haroon; Koel, Ants; Rang, Toomas Silicon carbide and related materials 2017 : ICSCRM 2017 : selected, peer reviewed papers from the 2017 International Conference on Silicon Carbide and related materials, September 17-22, 2017, Washington, DC, USA 2018 / p. 302-305 : ill <https://doi.org/10.4028/www.scientific.net/MSF.924.302> [Conference Proceedings at Scopus](#) [Article at Scopus](#)